

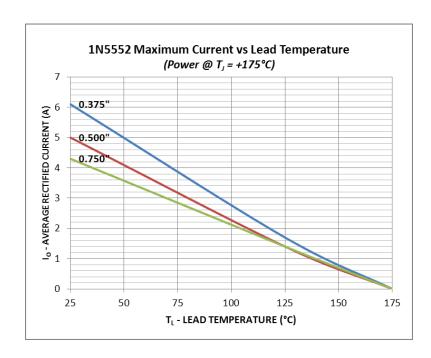
SENSITRON SEMICONDUCTOR

TECHNICAL DATA DATA SHEET 126, REV G.1

RATING	CONDITIONS	MIN	TYP	MAX	UNIT
Maximum Instantaneous Reverse Current At Rated (PIV)	T _A = 25° C	-	-	1.0	μAmps
	T _A = 100° C			60	
Reverse Recovery Time (t _{rr})	$I_f = 0.5A, I_r = 1.0A, I_{rr}$ = 0.25A	-	-	2000	nsec
Thermal Resistance (θ _{JL})	Junction to Lead			22	°C/W
	d = 0.375"				
Thermal Resistance (θ_{JEC})	Junction to Endcap	-	-	6.5	° C/W

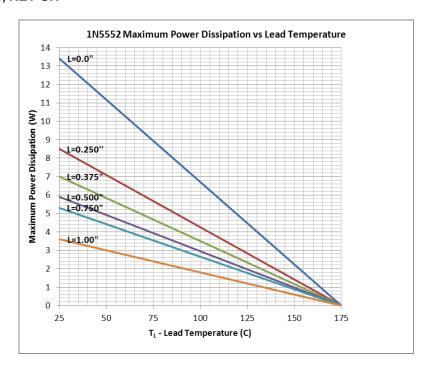
^{*}Sensitron **space equivalent diodes** are manufactured and screened to MIL-PRF-19500 flow and guidelines starting from wafer fabrication through assembly and testing using our internal specification.

GRAPHS:



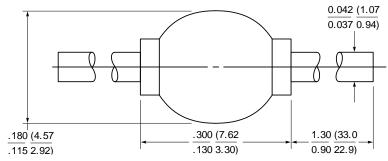
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PACKAGE DIMENSIONS (inches/mm)

AXIAL (PKG 301)



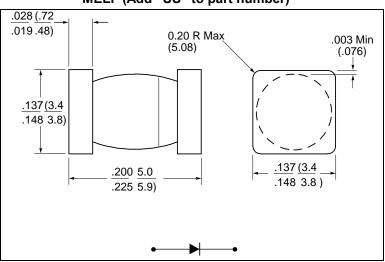
Note: The cathode side is marked with a dark colored band on one side of the diode body.

SENSITRON SEMICONDUCTOR 3A STANDARD RECOVERY RECTIFIERS

MELF-B

TECHNICAL DATA DATA SHEET 126, REV G.1

MELF (Add "US" to part number)



Note: The cathode side is marked on body with a dark band.

PART ORDERING INFORMATION

The following part numbers can be screened and tested to the military screening flow. The parts are marked in accordance with the testing performed, example:

accordance man are teening performed, examples					
Sensitron Screening Level	*Part Number Leaded Package (example for 1N5550)	*Part Number Surface Mount Package (example for 1N5550US)			
1N	1N5550	1N5550US			
JAN	JAN1N5550	JAN1N5550US			
JANTX	JANTX1N5550	JANTX1N5550US			
JANTXV	JANTXV1N5550	JANTXV1N5550US			
SJ	SJ5550	SJ5550US			
SX	SX5550	SX5550US			
SV	SV5550	SV5550US			
JANS	JANS1N5550	JANS1N5550US			
SS	SS5550	SS5550US			

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